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LISTOF	REFE	RENCES CITED BY AP	PLICANIT	Yoshihisa IWATA et al.					
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		13		U.S. PATENT DOCUME	NTS				
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77	Takeshi HONDA et al., "MRAM-Writing Circuitry to Compensate for Thermal-Variation of Magnetization-Reversal Current", AW 2002 Symposium On VLSI Circuits Digest of Technical Papers, IEEE, June 2002, pp. 156-157.								
	AX								
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	AZ				Additional References sheet(s) attached				
Examiner	Trong Phan					Date Considered 1/31/06			
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Oraw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.									